

Vishay Semiconductors

FlipKY[®], 1.5 A Chip Scale Package Schottky Barrier Rectifier



FlipKY®

PRODUCT SUMMARY I_{F(AV)} 1.5 A V_R 40 V V_F at I_F 0.47 V I_{RM} max. at 25 °C 15 μA I_{RM} max. at 125 °C 4 mA T_J max. 150 °C E_{AS} 10 mJ

FEATURES

- Ultra low V_F per footprint area
- · Low leakage
- · Low thermal resistance
- · One-fifth footprint of SMA
- Super low profile (0.6 mm)
- Available tested on tape and reel
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- · Reverse polarity protection
- · Current steering
- Freewheeling
- Flyback
- Oring

DESCRIPTION

Vishay's FlipKY® product family utilizes wafer level chip scale packaging to deliver Schottky diodes with the lowest V_F to PCB footprint area in industry. The four bump 1.5 mm x 1.5 mm devices can deliver up to 1.5 A and occupy only 2.3 mm² of board space. The anode and cathode connections are made through solder bump pads on one side of the silicon enabling designers to strategically place the diodes on the PCB. This design not only minimizes board space but also reduces thermal resistance and inductance, which can improve overall circuit efficiency.

Typical applications include hand-held, portable equipment such as cell phones, MP3 players, bluetooth, GPS, PDAs, and portable hard disk drives where space savings and performance are crucial.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	MAX.	UNITS	
V _{RRM}		40	V	
I _{F(AV)}	Rectangular waveform	1.5	Δ.	
I _{FSM}		250	A	
V _F	1.5 A _{pk} , T _J = 125 °C	0.47	V	
T _J		- 55 to 150	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-FCSP2H40LTR	UNITS	
Maximum DC reverse voltage	V_{R}	40	V	
Maximum working peak reverse voltage	V_{RWM}	40	V	



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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)} 50 % duty cycle at T _{PCB} = 102 °C, rectangular waveform		1.5		
Maximum peak one cycle	I _{FSM} load condition and	5 μs sine or 3 μs rect. pulse	Following any rated	250	Α
non-repetitive surge current at 25 °C		rated V _{RRM} applied	21		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2.0 A, L = 5.0 mH		10	mJ
Repetitive avalanche current I_{AR} Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		2.0	Α		

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
		1.5 A	T _{.1} = 25 °C	0.52	0.56	V
Maximum forward voltage drop	V _{FM} ⁽¹⁾	3 A	11 = 25 G	0.60	0.65	
See fig. 1	VFM (*)	1.5 A	T = 125 °C	0.42	0.47	
		3 A	T _J = 125 °C	0.54	0.59	
			V _R = Rated V _R	3	15	μΑ
		T 05 %C	V _R = 20 V	0.5	1	
		T _J = 25 °C	V _R = 10 V	0.2	0.5	
Maximum reverse leakage current	I _{RM} ⁽¹⁾		V _R = 5 V	0.2 0.15 2.5	0.3	
See fig. 2	IRM ('')		V _R = Rated V _R		4	
		T 105 °C	V _R = 20 V	0.9	2	A
		T _J = 125 °C	V _R = 10 V	0.6	1.5	mA .
			V _R = 5 V	0.5	1	
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		-	160	pF
Maximum voltage rate of charge d		Rated V _R		-	10 000	V/µs

Note

 $^{^{(1)}~}$ Pulse width $<300~\mu s,~duty~cycle < 2~\%$

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 55 to 150	°C	
Typical thermal resistance, junction to PCB	R _{thJL} (2)	DC operation	40	°C/W	
Maximum thermal resistance, junction to ambient RthJA			62	C/VV	

Notes

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

⁽²⁾ Mounted 1" square PCB



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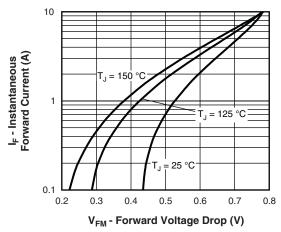


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

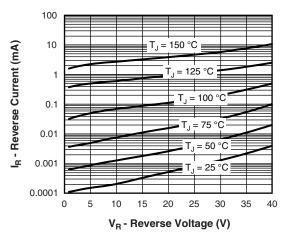


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

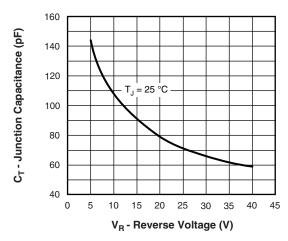
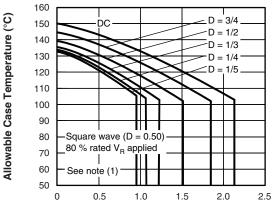


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)



 $I_{F(AV)}$ - Average Forward Current (A)

Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

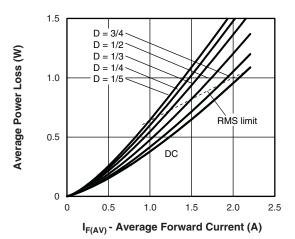


Fig. 5 - Forward Power Loss Characteristics (Per Leg)

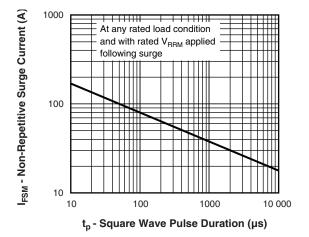


Fig. 6 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

(1) Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at 80 % V_R applied



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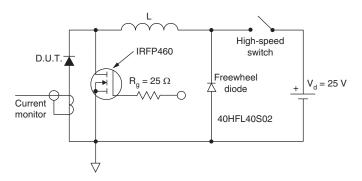


Fig. 7 - Unclamped Inductive Test Circuit

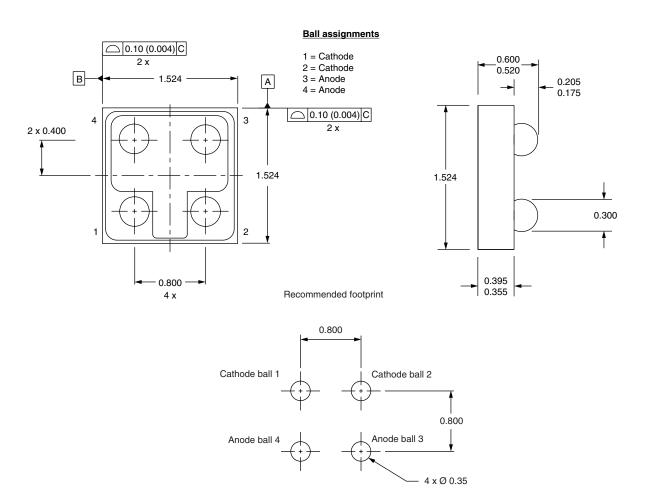
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95282</u>				
Part marking information	www.vishay.com/doc?95281			
Packaging information	www.vishay.com/doc?95062			



Vishay High Power Products

FlipKY® 1 A/1.5 A (Large Bump Pad Design)

DIMENSIONS in millimeters



Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Controlling dimension: millimeter





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